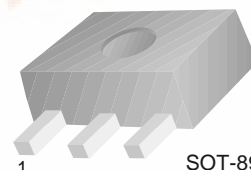




KSC2982

Strobe Flash & Medium Power Amplifier

- Excellent h_{FE} Linearity : $h_{FE1}=140 \sim 600$
- Low Collector-Emitter Saturation Voltage : $V_{CE(sat)}=0.5V$
- Collector Dissipation : $P_C=1\sim 2W$ in Mounted on Ceramic Board



SOT-89
1. Base 2. Collector 3. Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------|-----------------------------|-----------|------------|
| V_{CBO} | Collector-Base Voltage | 30 | V |
| V_{CES} | Collector-Emitter Voltage | 30 | V |
| V_{CEO} | Collector-Emitter Voltage | 10 | V |
| V_{EBO} | Emitter Base Voltage | 6 | V |
| I_C | Collector Current (DC) | 2 | A |
| I_{CP} | * Collector Current (Pulse) | 4 | A |
| I_B | Base Current (DC) | 0.4 | A |
| I_{BP} | * Base Current (Pulse) | 0.8 | A |
| P_C | Collector Power Dissipation | 500 | mW |
| P_C^* | | 1,000 | mW |
| T_J | Junction Temperature | 150 | $^\circ C$ |
| T_{STG} | Storage Temperature | -55 ~ 150 | $^\circ C$ |

* $PW \leq 10ms$, Duty Cycles $\leq 30\%$

Mounted on Ceramic Board (250mm² x 0.8mm)

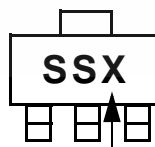
Electrical Characteristics $T_a=25^\circ C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---------------|--------------------------------------|-----------------------------|------|------|------|-------|
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C=10mA, I_B=0$ | 10 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E=1mA, I_C=0$ | 6 | | | V |
| I_{CBO} | Collector Cut-off Current | $V_{CB}=30V, I_E=0$ | | | 100 | nA |
| I_{EBO} | Emitter Cut-off Current | $V_{BE}=6V, I_C=0$ | | | 100 | nA |
| h_{FE1} | DC Current Gain | $V_{CE}=1V, I_C=0.5A$ | 140 | | 600 | |
| h_{FE2} | | $V_{CE}=1V, I_C=2A$ | 70 | 140 | | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=2A, I_B=50mA$ | | 0.2 | 0.5 | V |
| $V_{BE(on)}$ | Base-Emitter On Voltage | $V_{CE}=1V, I_C=2A$ | | 0.86 | 1.5 | V |
| f_T | Current Gain Bandwidth Product | $V_{CE}=1V, I_C=2A$ | | 150 | | MHz |
| C_{ob} | Output Capacitance | $V_{CB}=10V, I_E=0, f=1MHz$ | | 27 | | pF |

h_{FE1} Classification

| Classification | A | B | C | D |
|----------------|-----------|-----------|-----------|-----------|
| h_{FE1} | 140 ~ 240 | 200 ~ 330 | 300 ~ 450 | 420 ~ 600 |

Marking



h_{FE} grade

Typical Characteristics

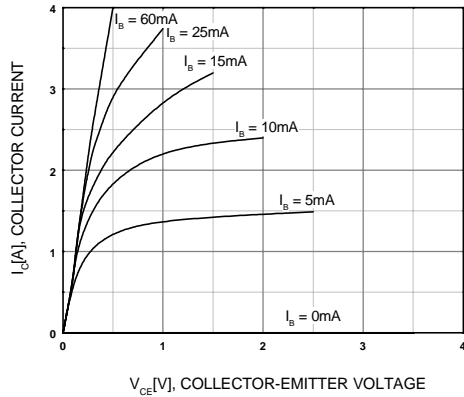


Figure 1. Static Characteristic

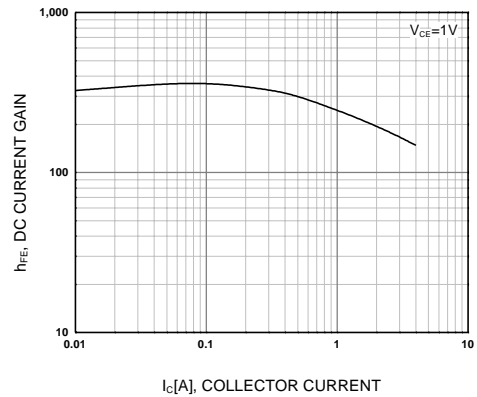


Figure 2. DC current Gain

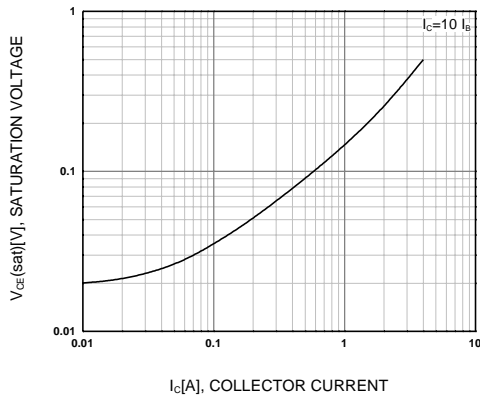


Figure 3. Collector-Emitter Saturation Voltage

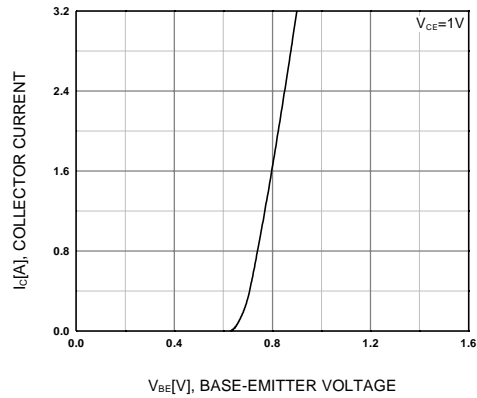


Figure 4. Base-Emitter On Voltage

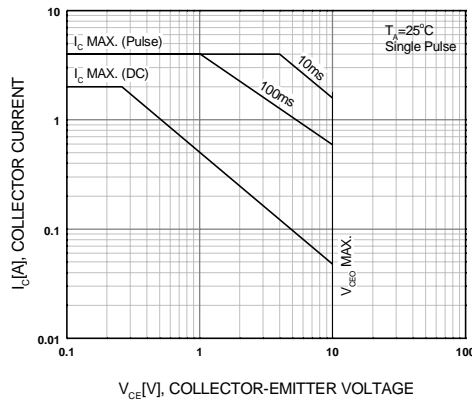


Figure 5. Safe Operating Area

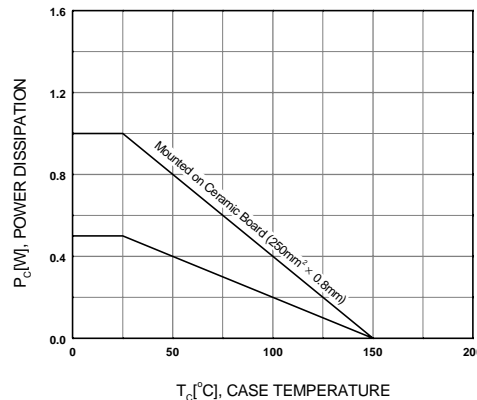
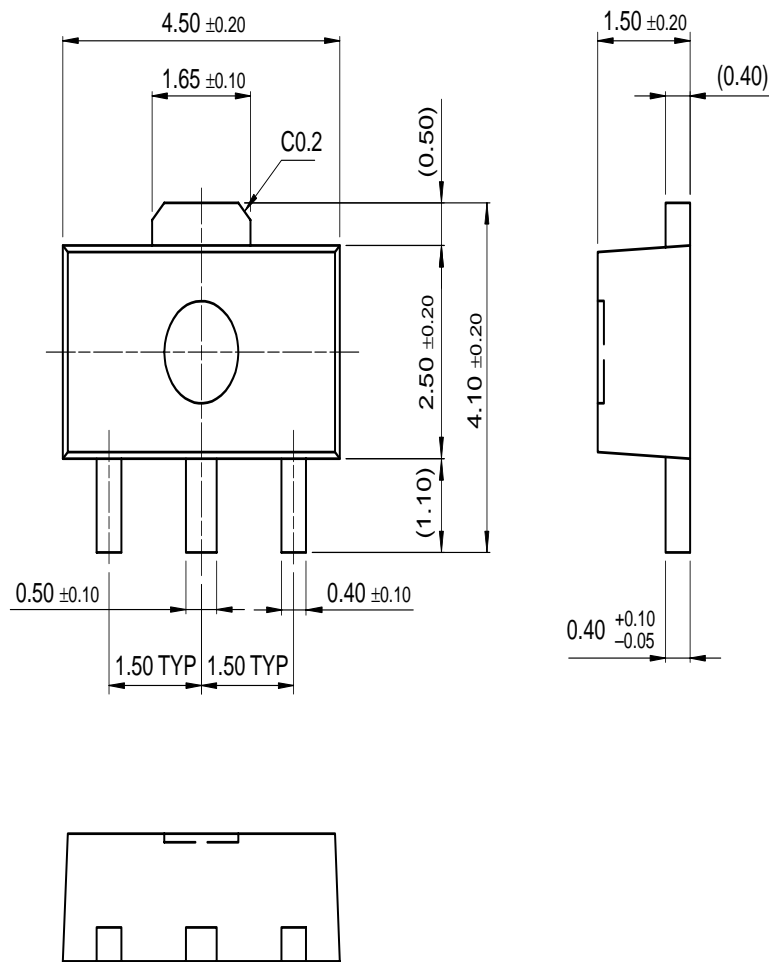


Figure 6. Power Derating

Package Dimensions

SOT-89



Dimensions in Millimeters

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| Bottomless™ | FAST® | LittleFET™ | Power247™ | SuperSOT™-3 |
| CoolFET™ | FASTr™ | MicroFET™ | PowerTrench® | SuperSOT™-6 |
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| DOMET™ | GlobalOptoisolator™ | MICROWIRE™ | QS™ | SyncFET™ |
| EcoSPARK™ | GTO™ | MSX™ | QT Optoelectronics™ | TinyLogic® |
| E ² CMOS™ | HiSeC™ | MSXPro™ | Quiet Series™ | TruTranslation™ |
| EnSigna™ | I ² C™ | OCX™ | RapidConfigure™ | UHC™ |
| Across the board. Around the world.™ | | OCXPro™ | RapidConnect™ | UltraFET® |
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|--------------------------|------------------------|---|
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